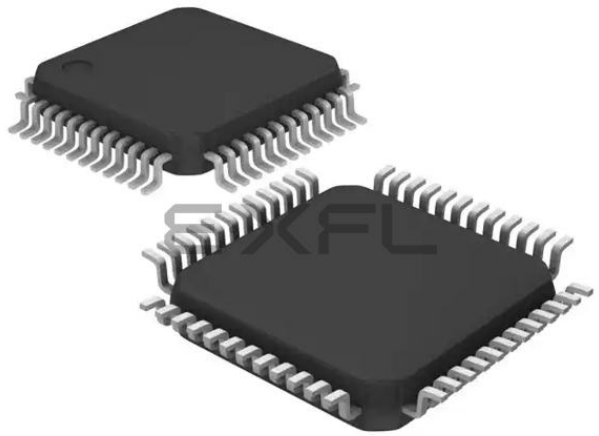
Renesas Electronics America Inc - R5F10EGEAFB#V0 Datasheet



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What is "Embedded - Microcontrollers"?

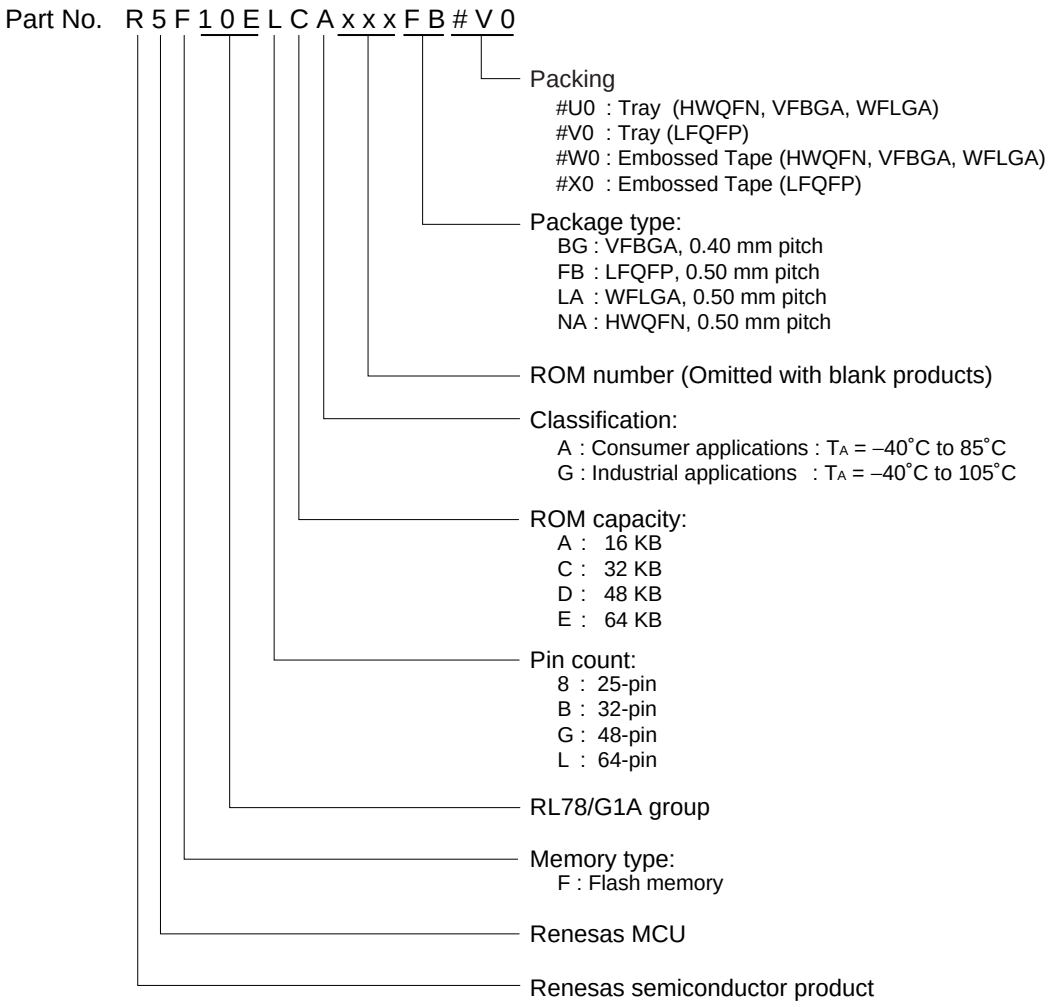
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I²C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	32
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 3.6V
Data Converters	A/D 24x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LFQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10egeafb-v0

1.2 List of Part Numbers

Figure 1-1. Part Number, Memory Size, and Package of RL78/G1A



Caution The part number above is valid as of when this manual was issued. For the latest part number, see the web page of the target product on the Renesas Electronics website.

1.3.3 48-pin products

- 48-pin plastic LFQFP (7 × 7 mm, 0.5 mm pitch)

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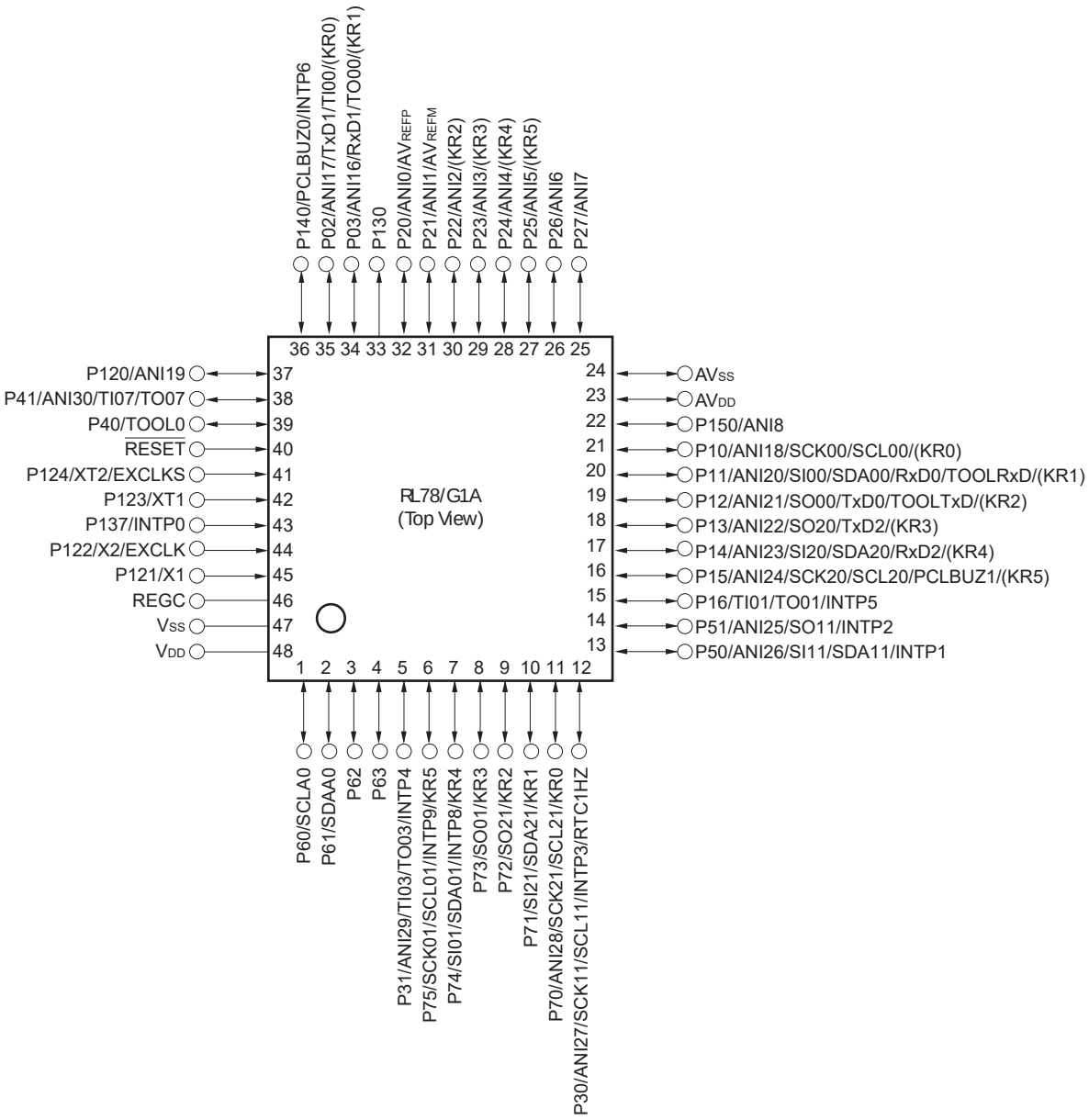
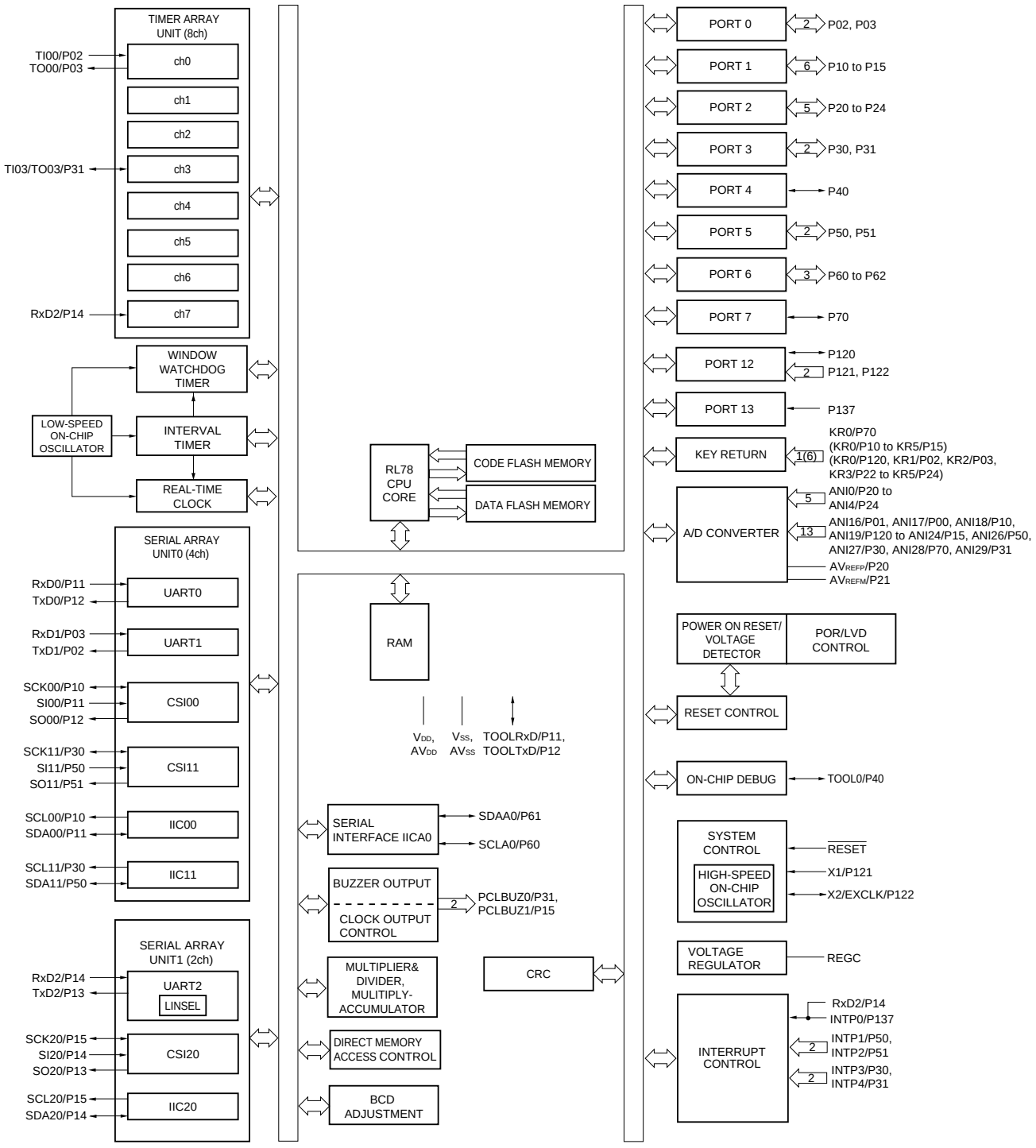


Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1 μF).

Remarks 1. For pin identification, see **1.4 Pin Identification**.

2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR).

<R> 1.5.2 32-pin products



Remark Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR).

(T_A = –40 to +85°C, 1.6 V ≤ AV_{DD} ≤ V_{DD} ≤ 3.6 V, 1.6 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V) **(5/5)**

Items	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Input leakage current, high	I_{LIH1}	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P60 to P63, P70 to P77, P120, P140, P141	V_I = EV_{DD0}				1	μA
	I_{LIH2}	P137, $\overline{RESET}$	V_I = V_{DD}				1	μA
	I_{LIH3}	P121 to P124 (X1, X2, XT1, XT2, EXCLK, EXCLKS)	V_I = V_{DD}	In input port or external clock input			1	μA
				In resonator connection			10	μA
	I_{LIH4}	P20 to P27, P150 to P154	V_I = AV_{DD}				1	μA
Input leakage current, low	I_{LIL1}	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P60 to P67, P70 to P77, P120, P140, P141	V_I = EV_{SS0}				–1	μA
	I_{LIL2}	P137, $\overline{RESET}$	V_I = V_{SS}				–1	μA
	I_{LIL3}	P121 to P124 (X1, X2, XT1, XT2, EXCLK, EXCLKS)	V_I = V_{SS}	In input port or external clock input			–1	μA
				In resonator connection			–10	μA
	I_{LIL4}	P20 to P27, P150 to P154	V_I = AV_{SS}				–1	μA
On-chip pull-up resistance	R_U	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P70 to P77, P120, P140, P141	V_I = EV_{SS0}, In input port		10	20	100	kΩ

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Notes 1. Total current flowing into V_{DD} and EV_{DD0}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD}, EV_{DD0} or V_{SS}, EV_{SS0}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, on-chip pull-up/pull-down resistors, and data flash rewriting.

2. During HALT instruction execution by flash memory.

3. When high-speed on-chip oscillator and subsystem clock are stopped.

4. When high-speed system clock and subsystem clock are stopped.

5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). Including the current flowing into the RTC. However, not including the current flowing into the 12-bit interval timer, and watchdog timer.

6. When subsystem clock is stopped. Not including the current flowing into the RTC, 12-bit interval timer, watchdog timer.

7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: 2.7 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 32 MHz
2.4 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 16 MHz
LS (low-speed main) mode: 1.8 V ≤ V_{DD} < 3.6 V@1 MHz to 8 MHz
LV (low-voltage main) mode: 1.6 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 4 MHz

8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

Remarks 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2. f_{IH}: High-speed on-chip oscillator clock frequency

3. f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)

4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T_A = 25°C

(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)

(T_A = –40 to +85°C, 2.7 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions		HS[Note 1]		LS[Note 2]		LV[Note 3]		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t_{KCY1}	2.7 V ≤ EV_{DD} ≤ 3.6 V	t_{KCY1} ≥ 2/f_{CLK}	83.3		250		500		ns
SCKp high-/low-level width	t_{KH1}, t_{KL1}	2.7 V ≤ EV_{DD} ≤ 3.6 V		t_{KCY1}/2 –10		t_{KCY1}/2 –50		t_{KCY1}/2 –50		ns
SIp setup time (to SCKp↑)[Note 4]	t_{SIK1}	2.7 V ≤ EV_{DD} ≤ 3.6 V		33		110		110		ns
SIp hold time (from SCKp↑)[Note 4]	t_{KSI1}	2.7 V ≤ EV_{DD} ≤ 3.6 V		10		10		10		ns
Delay time from SCKp↓ to SOp output[Note 5]	t_{KSO1}	C = 20 pF[Note 6]			10		10		10	ns

Notes 1. HS is condition of HS (high-speed main) mode.

2. LS is condition of LS (low-speed main) mode.

3. LV is condition of LV (low-voltage main) mode.

4. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time or SIp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

6. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the SIp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remarks 1. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM and POM numbers (g = 1)

2. f_{MCK}: Serial array unit operation clock frequency (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

Notes 1. HS is condition of HS (high-speed main) mode.

2. LS is condition of LS (low-speed main) mode.

3. LV is condition of LV (low-voltage main) mode.

4. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

5. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time or SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

6. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

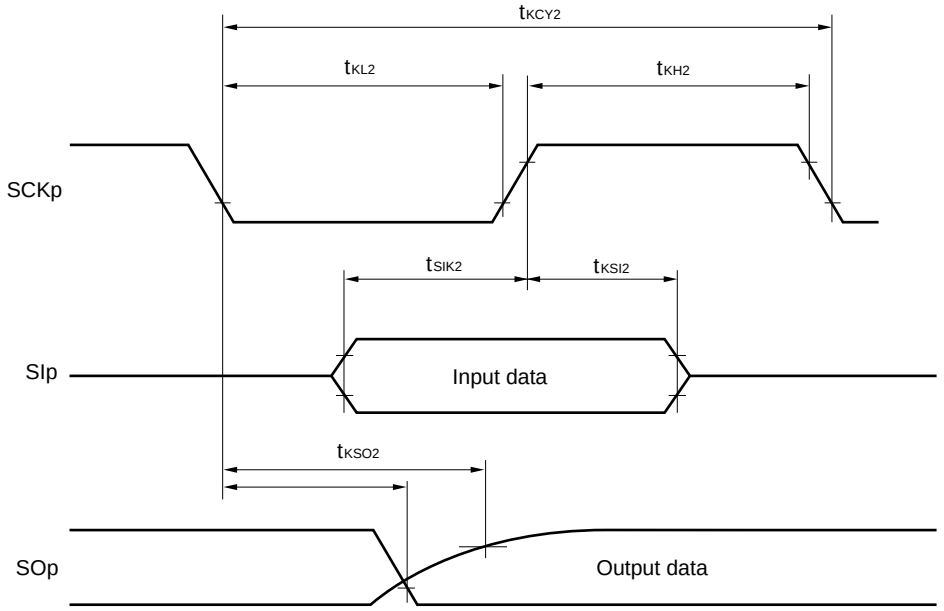
7. C is the load capacitance of the SOp output lines.

Caution Select the normal input buffer for the SIp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

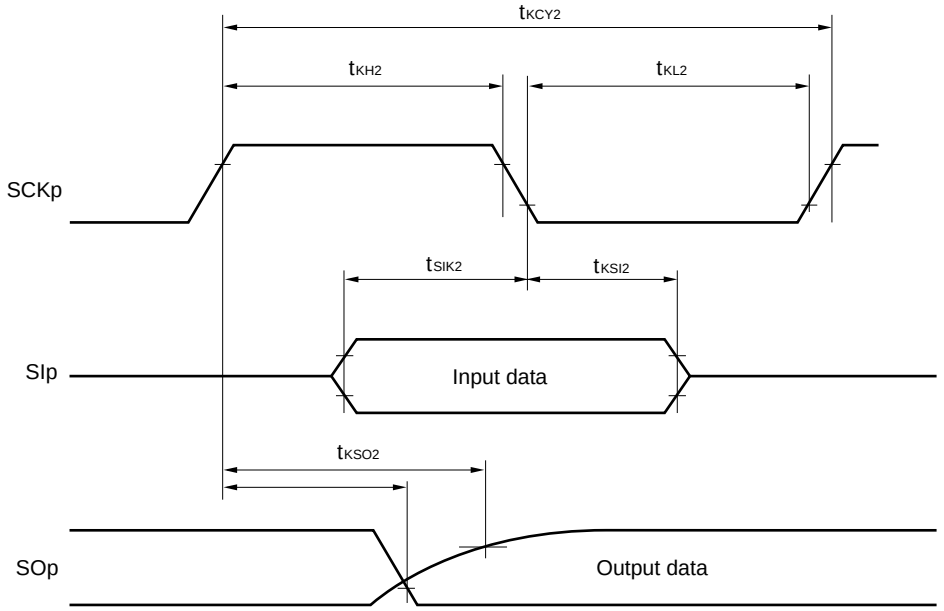
Remarks 1. p: CSI number (p = 00, 01, 10, 11, 20, 21), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),
g: PIM number (g = 0, 1)

2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

CSI mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



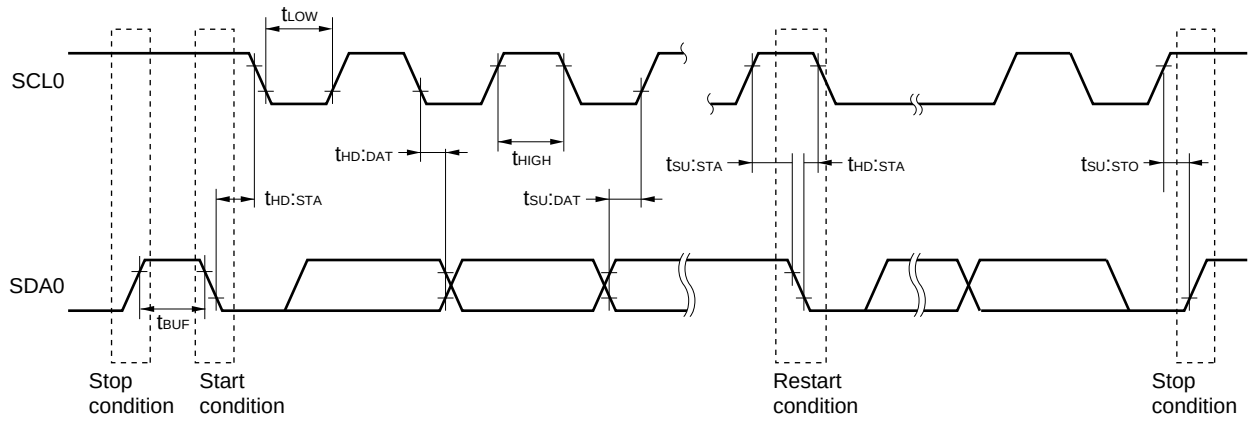
CSI mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remarks 1. p: CSI number (p = 00, 10, 20), m: Unit number, n: Channel number (mn = 00, 02, 10), g: PIM and POM number (g = 0, 1)

2. CSI01, CSI11, and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

IICA serial transfer timing



<R> **(3) When reference voltage (+) = AV_{DD} (ADREFP1 = 0, ADREFP0 = 0), reference voltage (–) = AV_{SS} (ADREFM = 0), target for conversion: ANI0 to ANI12**

(T_A = –40 to +85°C, 1.6 V ≤ AV_{DD} ≤ V_{DD} ≤ 3.6 V, V_{SS} = 0 V, AV_{SS} = 0 V, Reference voltage (+) = AV_{DD}, Reference voltage (–) = AV_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	R_{ES}		2.4 V ≤ AV_{DD} ≤ 3.6 V	8		12	bit
			1.8 V ≤ AV_{DD} ≤ 3.6 V	8		10 Note 1	
			1.6 V ≤ AV_{DD} ≤ 3.6 V	8 Note 2			
Overall error Note 3	AINL	12-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V			±7.5	LSB
		10-bit resolution	1.8 V ≤ AV_{DD} ≤ 3.6 V			±5.5	
		8-bit resolution	1.6 V ≤ AV_{DD} ≤ 3.6 V			±3.0	
Conversion time	t_{CONV}	ADTYP = 0, 12-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V	3.375			μs
		ADTYP = 0, 10-bit resolution Note 1	1.8 V ≤ AV_{DD} ≤ 3.6 V	6.75			
		ADTYP = 0, 8-bit resolution Note 2	1.6 V ≤ AV_{DD} ≤ 3.6 V	13.5			
		ADTYP = 1, 8-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V	2.5625			
			1.8 V ≤ AV_{DD} ≤ 3.6 V	5.125			
			1.6 V ≤ AV_{DD} ≤ 3.6 V	10.25			
Zero-scale error Note 3	E_{ZS}	12-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V			±6.0	LSB
		10-bit resolution	1.8 V ≤ AV_{DD} ≤ 3.6 V			±5.0	
		8-bit resolution	1.6 V ≤ AV_{DD} ≤ 3.6 V			±2.5	
Full-scale error Note 3	E_{FS}	12-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V			±6.0	LSB
		10-bit resolution	1.8 V ≤ AV_{DD} ≤ 3.6 V			±5.0	
		8-bit resolution	1.6 V ≤ AV_{DD} ≤ 3.6 V			±2.5	
Integral linearity error Note 3	ILE	12-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V			±3.0	LSB
		10-bit resolution	1.8 V ≤ AV_{DD} ≤ 3.6 V			±2.0	
		8-bit resolution	1.6 V ≤ AV_{DD} ≤ 3.6 V			±1.5	
Differential linearity error Note 3	DLE	12-bit resolution	2.4 V ≤ AV_{DD} ≤ 3.6 V			±2.0	LSB
		10-bit resolution	1.8 V ≤ AV_{DD} ≤ 3.6 V			±2.0	
		8-bit resolution	1.6 V ≤ AV_{DD} ≤ 3.6 V			±1.5	
<R> Analog input voltage	V_{AIN}			0		AV_{DD}	V

Notes 1. Cannot be used for lower 2 bit of ADCR register

2. Cannot be used for lower 4 bit of ADCR register

3. Excludes quantization error (±1/2 LSB).

<R> **(6) When reference voltage (+) = Internal reference voltage (1.45 V) (ADREFP1 = 1, ADREFP0 = 0), reference voltage (–) = AV_{SS} (ADREFM = 0), target ANI pin: ANI0 to ANI12, ANI16 to ANI30**

(T_A = –40 to +85°C, 2.4 V ≤ V_{DD} ≤ 3.6 V, 1.6 V ≤ EV_{DD} ≤ V_{DD}, 1.6 V ≤ AV_{DD} ≤ V_{DD}, V_{SS} = EV_{SS0} = 0 V, AV_{SS} = 0 V, Reference voltage (+) = Internal reference voltage, Reference voltage (–) = AV_{SS} = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	R_{ES}			8		bit
Conversion time	t_{CONV}	8-bit resolution	16			μs
Zero-scale error[Note]	E_{ZS}	8-bit resolution			±4.0	LSB
Integral linearity error[Note]	ILE	8-bit resolution			±2.0	LSB
Differential linearity error[Note]	DLE	8-bit resolution			±2.5	LSB
Reference voltage (+)	$AV_{REF(+)}$	= Internal reference voltage (V_{BGR})	1.38	1.45	1.5	V
Analog input voltage	V_{AIN}		0		V_{BGR}	V

Note Excludes quantization error (±1/2 LSB).

2.6.2 Temperature sensor, internal reference voltage output characteristics

(T_A = –40 to +85°C, 2.4 V ≤ V_{DD} ≤ 3.6 V, V_{SS} = 0 V, HS (high-speed main) mode)

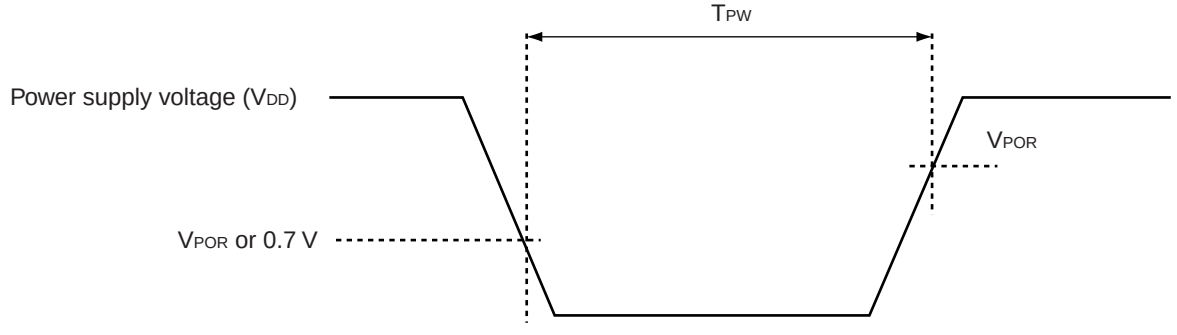
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	V_{TMPS25}	Setting ADS register = 80H, T_A = +25°C		1.05		V
Internal reference voltage	V_{BGR}	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	F_{VTMPS}	Temperature sensor output voltage that depends on the temperature		–3.6		mV/°C
Operation stabilization wait time	t_{AMP}		10			μs

2.6.3 POR circuit characteristics

(T_A = –40 to +85°C, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	V_{POR}	Power supply rise time	1.47	1.51	1.55	V
	V_{PDR}	Power supply fall time	1.46	1.50	1.54	V
Minimum pulse width[Note]	T_{PW}		300			μs

Note This is the time required for the POR circuit to execute a reset when V_{DD} falls below V_{PDR}. When the microcontroller enters STOP mode or if the main system clock (f_{MAIN}) has been stopped by setting bit 0 (HIOSTOP) and bit 7 (MSTOP) of the clock operation status control register (CSC), this is the time required for the POR circuit to execute a reset before V_{DD} rises to V_{POR} after having fallen below 0.7 V.



(T_A = –40 to +105°C, 2.4 V ≤ AV_{DD} ≤ V_{DD} ≤ 3.6 V, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V) **(3/5)**

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Input voltage, high	V_{IH1}	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P70 to P77, P120, P140, P141	Normal input buffer	0.8EV_{DD0}		EV_{DD0}	V
	V_{IH2}	P01, P03, P04, P10, P11, P13 to P16, P43	TTL input buffer 3.3 V ≤ EV_{DD0} ≤ 3.6 V	2.0		EV_{DD0}	V
			TTL input buffer 2.4 V ≤ EV_{DD0} < 3.3 V	1.5		EV_{DD0}	V
	V_{IH3}	P20 to P27, P150 to P154		0.7AV_{DD}		AV_{DD}	V
	V_{IH4}	P60 to P63		0.7EV_{DD0}		6.0	V
	V_{IH5}	P121 to P124, P137, EXCLK, EXCLKS, $\overline{\text{RESET}}$		0.8V_{DD}		V_{DD}	V
Input voltage, low	V_{IL1}	P00 to P06, P10 to P16, P30, P31, P40 to P43, P50, P51, P70 to P77, P120, P140, P141	Normal input buffer	0		0.2EV_{DD0}	V
	V_{IL2}	P01, P03, P04, P10, P11, P13 to P16, P43	TTL input buffer 3.3 V ≤ EV_{DD0} ≤ 3.6 V	0		0.5	V
			TTL input buffer 2.4 V ≤ EV_{DD0} < 3.3 V	0		0.32	V
	V_{IL3}	P20 to P27, P150 to P154		0		0.3AV_{DD}	V
	V_{IL4}	P60 to P63		0		0.3EV_{DD0}	V
	V_{IL5}	P121 to P124, P137, EXCLK, EXCLKS, $\overline{\text{RESET}}$		0		0.2V_{DD}	V

Caution The maximum value of V_{IH} of pins P00, P02 to P04, P10 to P15, P43, P50, P71, and P74 is EV_{DD0}, even in the N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V) **(2/3)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current[Note 1]	I_{DD2}[Note 2]	HALT mode	HS (high-speed main) mode[Note 7]	f_{IH} = 32 MHz[Note 4]	V_{DD} = 3.0 V		0.54	2.90	mA
				f_{IH} = 24 MHz[Note 4]	V_{DD} = 3.0 V		0.44	2.30	mA
				f_{IH} = 16 MHz[Note 4]	V_{DD} = 3.0 V		0.40	1.70	mA
			HS (high-speed main) mode[Note 7]	f_{MX} = 20 MHz[Note 3], V_{DD} = 3.0 V	Square wave input		0.28	1.90	mA
					Resonator connection		0.45	2.00	
				f_{MX} = 10 MHz[Note 3], V_{DD} = 3.0 V	Square wave input		0.19	1.02	mA
					Resonator connection		0.26	1.10	
			Subsystem clock mode	f_{SUB} = 32.768 kHz[Note 5] T_A = –40°C	Square wave input		0.25	0.57	μA
					Resonator connection		0.44	0.76	
				f_{SUB} = 32.768 kHz[Note 5] T_A = +25°C	Square wave input		0.30	0.57	μA
					Resonator connection		0.49	0.76	
				f_{SUB} = 32.768 kHz[Note 5] T_A = +50°C	Square wave input		0.38	1.17	μA
					Resonator connection		0.57	1.36	
				f_{SUB} = 32.768 kHz[Note 5] T_A = +70°C	Square wave input		0.52	1.97	μA
					Resonator connection		0.71	2.16	
				f_{SUB} = 32.768 kHz[Note 5] T_A = +85°C	Square wave input		0.97	3.37	μA
					Resonator connection		1.16	3.56	
				f_{SUB} = 32.768 kHz[Note 5] T_A = +105°C	Square wave input		3.01	15.37	μA
					Resonator connection		3.20	15.56	
	I_{DD3}[Note 6]	STOP mode[Note 8]	T_A = –40°C				0.16	0.50	μA
			T_A = +25°C				0.23	0.50	
			T_A = +50°C				0.34	1.10	
			T_A = +70°C				0.46	1.90	
			T_A = +85°C				0.75	3.30	
			T_A = +105°C				2.94	15.30	

(**Notes** and **Remarks** are listed on the next page.)

Notes 1. Total current flowing into V_{DD} and EV_{DD0}, including the input leakage current flowing when the level of the input pin is fixed to V_{DD}, EV_{DD0} or V_{SS}, EV_{SS0}. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, on-chip pull-up/pull-down resistors, and data flash rewriting.

2. During HALT instruction execution by flash memory.

3. When high-speed on-chip oscillator and subsystem clock are stopped.

4. When high-speed system clock and subsystem clock are stopped.

5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). Including the current flowing into the RTC. However, not including the current flowing into the 12-bit interval timer, and watchdog timer.

6. When subsystem clock is stopped. Not including the current flowing into the RTC, 12-bit interval timer, watchdog timer.

7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: 2.7 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 32 MHz
2.4 V ≤ V_{DD} ≤ 3.6 V@1 MHz to 16 MHz

8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

Remarks 1. f_{MX}: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2. f_{IH}: High-speed on-chip oscillator clock frequency

3. f_{SUB}: Subsystem clock frequency (XT1 clock oscillation frequency)

4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T_A = 25°C

<R> **(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)**

(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
SCKp cycle time[Note 1]	t_{KCY2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V	16 MHz < f_{MCK}	16/f_{MCK}			ns
			f_{MCK} ≤ 16 MHz	12/f_{MCK}			ns
		2.4 V ≤ EV_{DD0} ≤ 3.6 V		12/f_{MCK} and 1000			ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V		t_{KCY2}/2–14			ns
		2.4 V ≤ EV_{DD0} ≤ 3.6 V		t_{KCY2}/2–16			ns
SIp setup time (to SCKp↑)[Note 2]	t_{SIK2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V		1/f_{MCK} + 40			ns
		2.4 V ≤ EV_{DD0} ≤ 3.6 V		1/f_{MCK} + 60			ns
SIp hold time (from SCKp↑)[Note 2]	t_{KSI2}	2.7 V ≤ EV_{DD0} ≤ 3.6 V		1/f_{MCK}+62			ns
		2.4 V ≤ EV_{DD0} ≤ 3.6 V		1/f_{MCK}+62			ns
Delay time from SCKp↓ to SOp output[Note 3]	t_{KSO2}	C = 30 pF[Note 4]	2.7 V ≤ EV_{DD0} ≤ 3.6 V			2/f_{MCK}+66	ns
			2.4 V ≤ EV_{DD0} ≤ 3.6 V			2/f_{MCK}+113	ns

Notes 1. Transfer rate in the SNOOZE mode : MAX. 1 Mbps

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time or SIp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

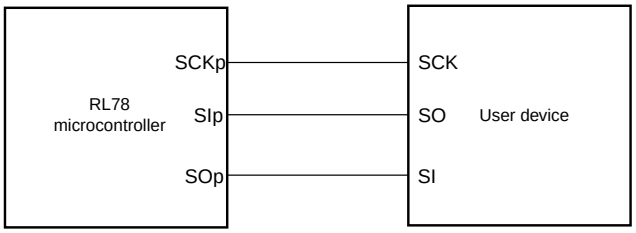
4. C is the load capacitance of the SOp output lines.

Caution Select the normal input buffer for the SIp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

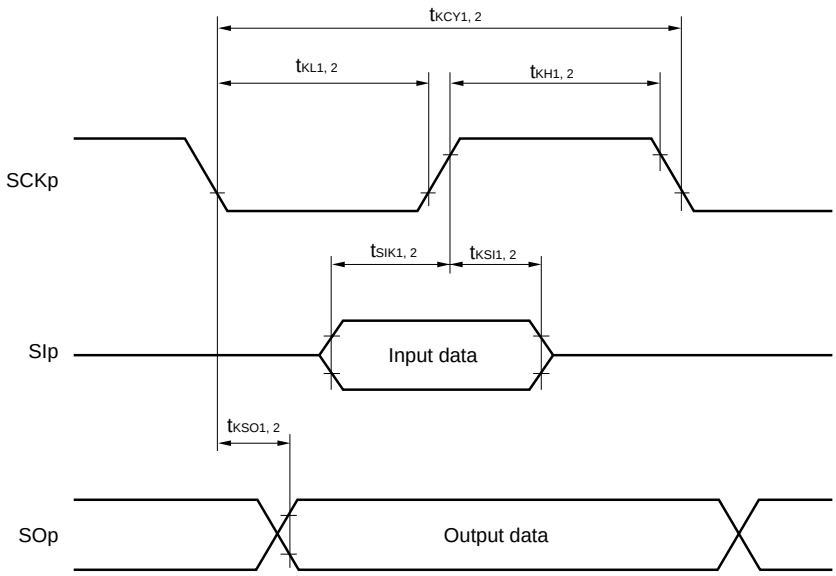
Remarks 1. p: CSI number (p = 00, 01, 10, 11, 20, 21), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),
g: PIM number (g = 0, 1)

2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

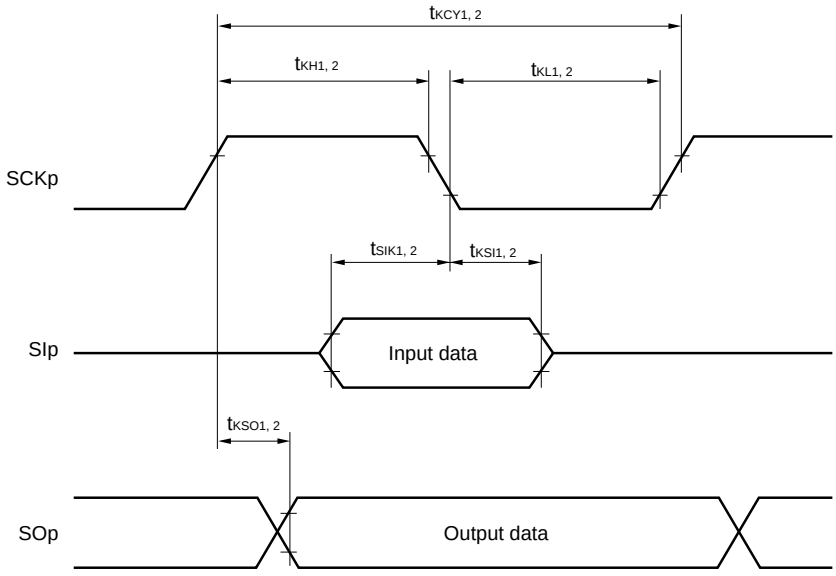
CSI mode connection diagram (during communication at same potential)



CSI mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



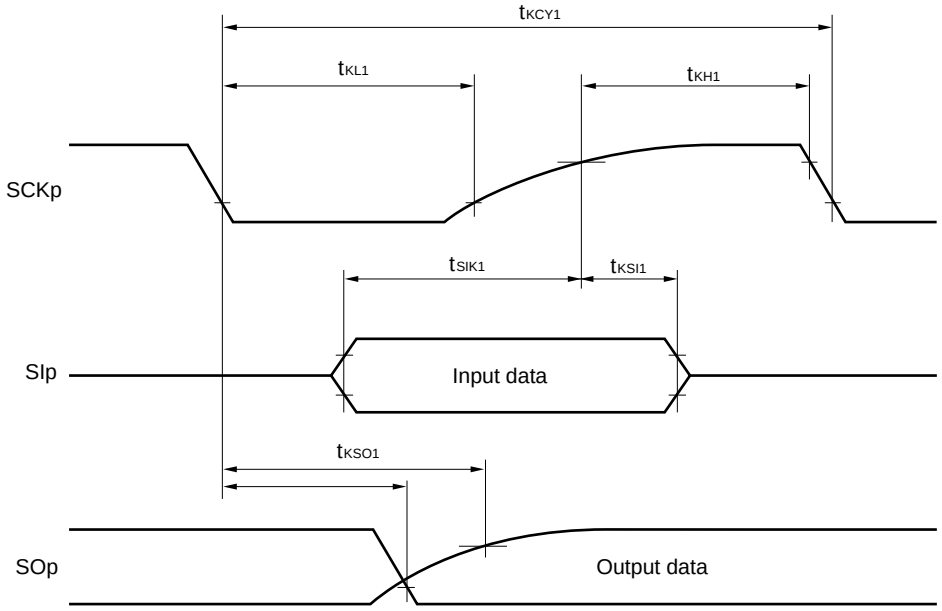
CSI mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



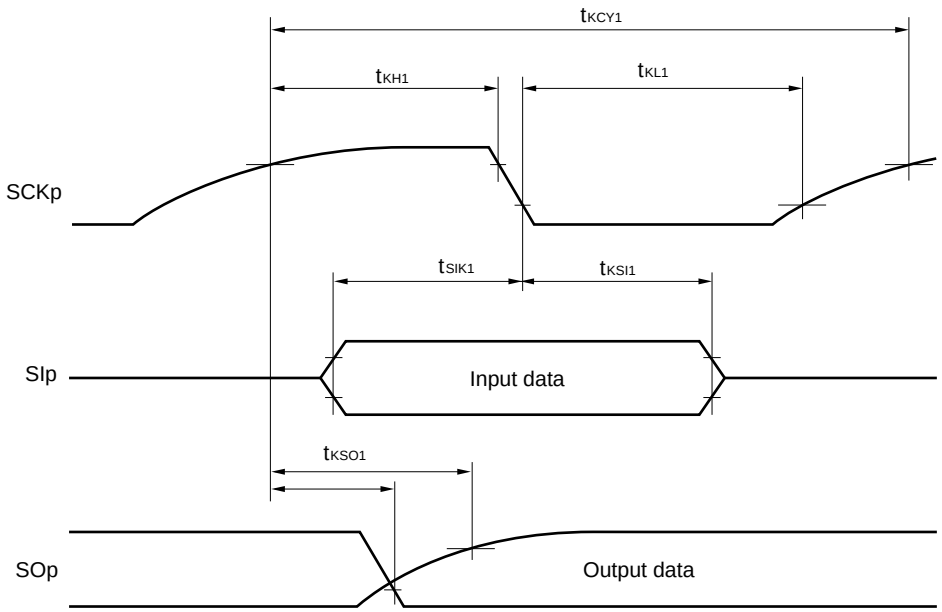
Remarks 1. p: CSI number (p = 00, 01, 10, 11, 20, 21)

2. m: Unit number, n: Channel number (mn = 00 to 03, 10, 11)

CSI mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remarks 1. p: CSI number (p = 00, 10, 20), m: Unit number, n: Channel number (m = 00, 02, 10), g: PIM and POM number (g = 0, 1)

2. CSI01, CSI11, and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

(8) Communication at different potential (1.8 V, 2.5 V) (simplified I^2C mode) (1/2)

(T_A = –40 to +105°C, 2.4 V ≤ EV_{DD0} ≤ V_{DD} ≤ 3.6 V, V_{SS} = EV_{SS0} = 0 V)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
SCLr clock frequency	f_{SCL}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ		400 Note 1	kHz
		2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ		100 Note 1	kHz
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ		100 Note 1	kHz
Hold time when SCLr = “L”	t_{LOW}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	1200		ns
		2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	4600		ns
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	4650		ns
Hold time when SCLr = “H”	t_{HIGH}	2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 50 pF, R_b = 2.7 kΩ	500		ns
		2.7 V ≤ EV_{DD0} ≤ 3.6 V, 2.3 V ≤ V_b ≤ 2.7 V, C_b = 100 pF, R_b = 2.7 kΩ	2400		ns
		2.4 V ≤ EV_{DD0} < 3.3 V, 1.6 V ≤ V_b ≤ 2.0 V, C_b = 100 pF, R_b = 5.5 kΩ	1830		ns

(**Notes**, **Caution** and **Remarks** are listed on the next page.)

4. PACKAGE DRAWINGS

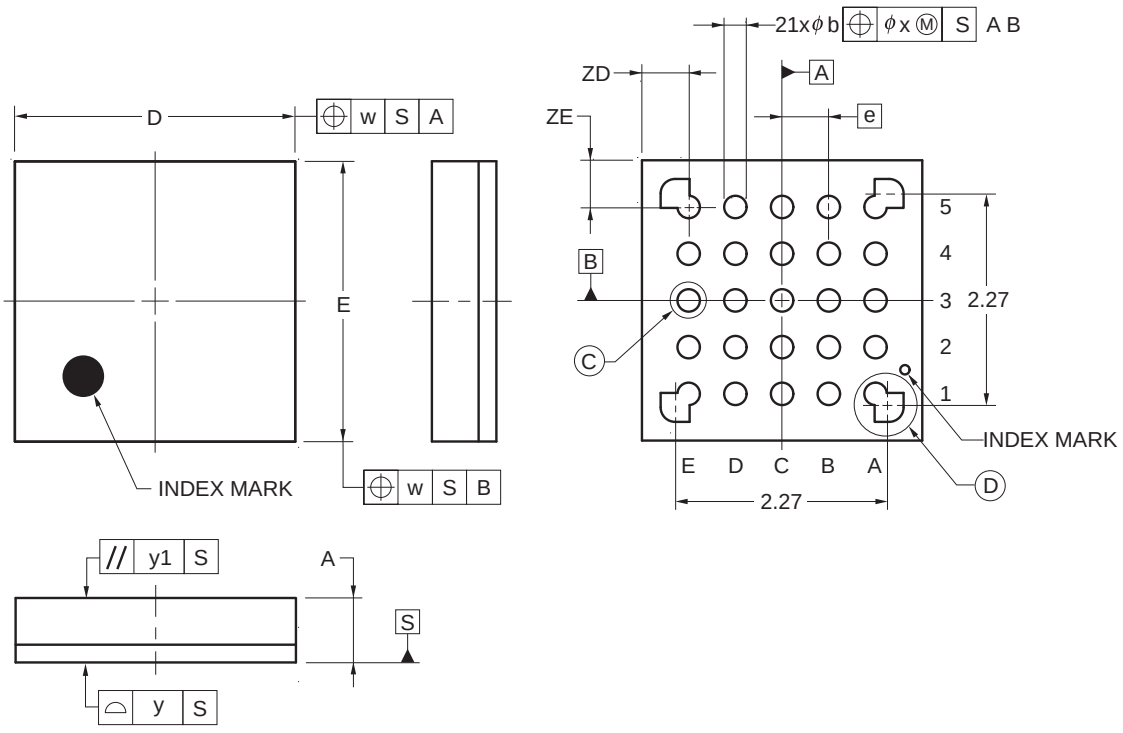
4.1 25-pin products

R5F10E8AALA, R5F10E8CALA, R5F10E8DALA, R5F10E8EALA

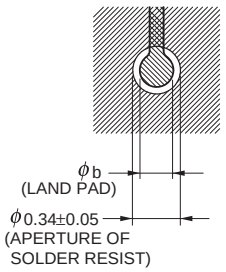
<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-WFLGA25-3x3-0.50	PWLG0025KA-A	P25FC-50-2N2-3	0.01

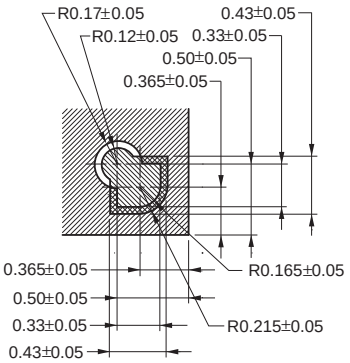
Unit: mm



DETAIL OF Ⓒ PART



DETAIL OF Ⓓ PART



ITEM	DIMENSIONS
D	3.00±0.10
E	3.00±0.10
w	0.20
e	0.50
A	0.69±0.07
b	0.24±0.05
x	0.05
y	0.08
y1	0.20
ZD	0.50
ZE	0.50

Rev.	Date	Description	
		Page	Summary
0.01	Dec 26, 2011	-	First Edition issued
1.00	Sep 25, 2013	p.1	Modification of 1.1 Features
		p.4	Modification of Table 1-1. List of Ordering Part Numbers
		p.6	Modification of Remark 3 to 1.3.2 32-pin products.
		p.13	Modification of 1.5.2 32-pin products.
		p.14	Modification of 1.5.3 48-pin products.
		p.16	Modification of 1.6 Outline of Functions
		p.21	Modification of 2.2.1 X1, XT1 oscillator characteristics
		p.31, 32	Modification of Note 1 in 2.3.2 Supply current characteristics
		p.34, 35	Modification of Minimum Instruction Execution Time during Main System Clock Operation
		p.37	Modification of AC Timing Test Points in 2.5 Peripheral Functions Characteristics
		p.46 to 58	Modification of Caution to 2.5.1 Serial array unit.
		p.63 to 68	Modification of 2.6.1 A/D converter characteristics
		p.71	Modification of 2.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics
		p.71	Modification of 2.8 Flash Memory Programming Characteristics
		p.72	Modification of 2.10 Timing Specs for Switching Flash Memory Programming Modes
		p.73 to 117	Addition of 3 ELECTRICAL SPECIFICATIONS (G: INDUSTRIAL APPLICATIONS T_A = −40 to +105°C)
		p.118 to 123	Modification of 4. PACKAGE DRAWINGS
2.10	Nov 30, 2016	p.4	Modification of Table 1-1. List of Ordering Part Numbers
		p.5 to 10	Modification of the position of the index mark in 1.3.1 25-pin products to 1.3.4 64-pin products
		p.6	Modification of Remark 3
		p.13	Modification of 1.5.2 32-pin products
		p.14	Modification of 1.5.3 48-pin products
		p.16	Modification of description in 1.6 Outline of Functions
		p.21	Modification of 2.2.1 X1, XT1 oscillator characteristics
		p.31, 32	Modification of Note 1 in 2.3.2 Supply current characteristics
		p.34, 35	Modification of Minimum Instruction Execution Time during Main System Clock Operation
		p.36	Modification of AC Timing Test Points and TI/TO Timing
		p.38	Modification of AC Timing Test Points in 2.5 Peripheral Functions Characteristics
		p.48, 50 to 52, 55, 59	Modification of Caution in 2.5.1 Serial array unit
		p.64 to 69	Modification of conditions of 2.6.1 A/D converter characteristics
		p.72	Renamed to 2.7 RAM Data Retention Characteristics, and modification of note and figure
		p.72	Modification of 2.8 Flash Memory Programming Characteristics